

## TURBO 2 ULTRAFAST HIGH VOLTAGE RECTIFIER

### MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	2 x 15 A
$V_{RRM}$	600 V
$I_{RM}$ (typ.)	8 A
$T_j$ (max)	175 °C
$V_F$ (max)	1.8 V
$t_{rr}$ (max)	50 ns

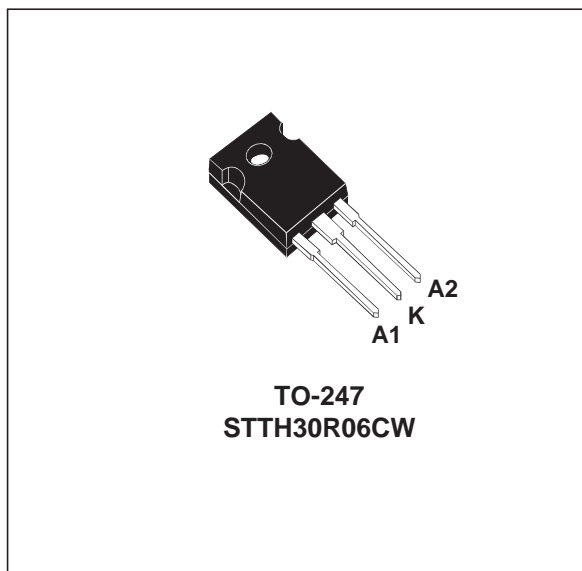
### FEATURES AND BENEFITS

- Ultrafast switching
- Low reverse recovery current
- Reduces switching losses
- Low thermal resistance

### DESCRIPTION

The STTH30R06CW, which is using ST Turbo 2 600V technology, is specially suited as boost diode in continuous mode power factor corrections and hard switching conditions.

The device is also intended for use as a free wheeling diode in power supplies and other power switching applications.



### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage		600	V
$I_{F(RMS)}$	RMS forward current		30	A
$I_{F(AV)}$	Average forward current	Per diode Per device	15 30	A
$I_{FSM}$	Surge non repetitive forward current	$t_p = 10$ ms Sinusoidal	120	A
$T_{stg}$	Storage temperature range		- 65 + 175	°C
$T_j$	Maximum operating junction temperature		175	°C

## STTH30R06CW

### THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
R <sub>th(j-c)</sub>	Junction to case	Per diode	1.5	°C/W
		Total	1.0	
R <sub>th(c)</sub>	Coupling	0.5		

### STATIC ELECTRICAL CHARACTERISTICS (per diode)

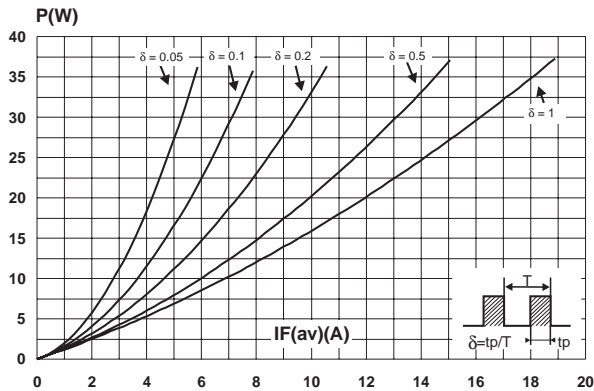
Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
I <sub>R</sub>	Reverse leakage current	V <sub>R</sub> = 600V	T <sub>j</sub> = 25°C			60	μA
			T <sub>j</sub> = 125°C		70	800	
V <sub>F</sub>	Forward voltage drop	I <sub>F</sub> = 15 A	T <sub>j</sub> = 25°C			2.9	V
			T <sub>j</sub> = 125°C		1.4	1.8	

To evaluate the maximum conduction losses use the following equation :  
 $P = 1.16 \times I_{F(AV)} + 0.043 I_{F(RMS)}^2$

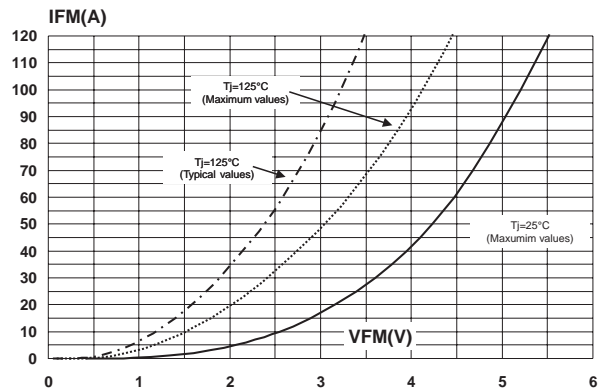
### DYNAMIC ELECTRICAL CHARACTERISTICS

Symbol	Tests conditions		Min.	Typ.	Max.	Unit
trr	I <sub>F</sub> = 0.5 A I <sub>rr</sub> = 0.25 A I <sub>R</sub> = 1A	T <sub>j</sub> = 25°C			30	ns
	I <sub>F</sub> = 1 A dI <sub>F</sub> /dt = - 50 A/μs V <sub>R</sub> = 30V				50	
I <sub>RM</sub>	V <sub>R</sub> = 400 V I <sub>F</sub> = 15A dI <sub>F</sub> /dt = - 200A/μs	T <sub>j</sub> = 125°C		7.5	9.0	A
S factor				0.15		
Q <sub>rr</sub>				220		nC
t <sub>fr</sub>	I <sub>F</sub> = 15 A dI <sub>F</sub> /dt = 120 A/μs V <sub>FR</sub> = 1.1 x V <sub>Fmax</sub>	T <sub>j</sub> = 25°C			200	ns
V <sub>FP</sub>					6	V

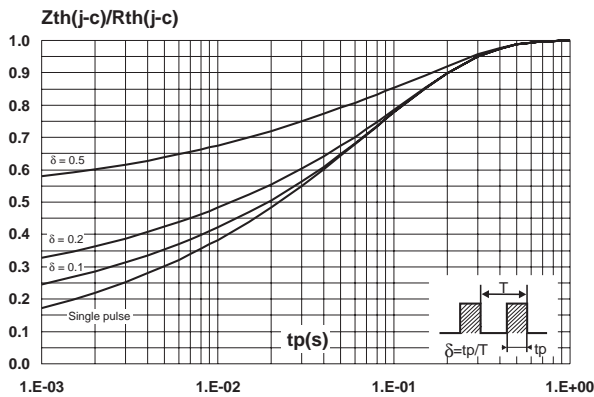
**Fig. 1:** Conduction losses versus average current (per leg).



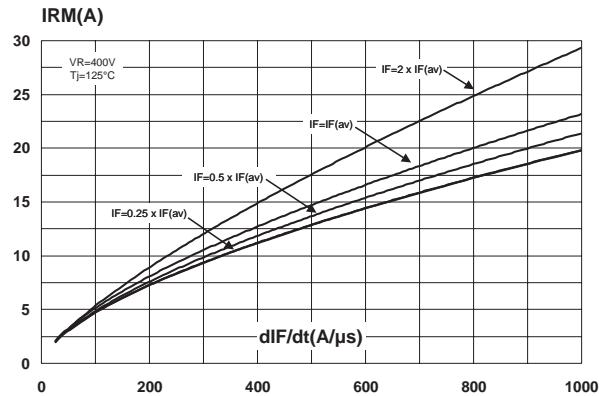
**Fig. 2:** Forward voltage drop versus forward current (per leg).



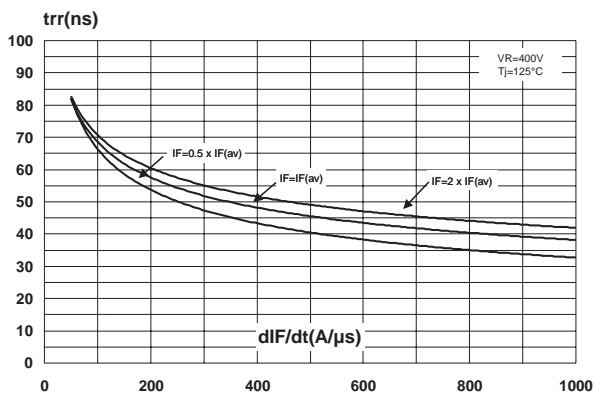
**Fig. 3:** Relative variation of thermal impedance junction to case versus pulse duration.



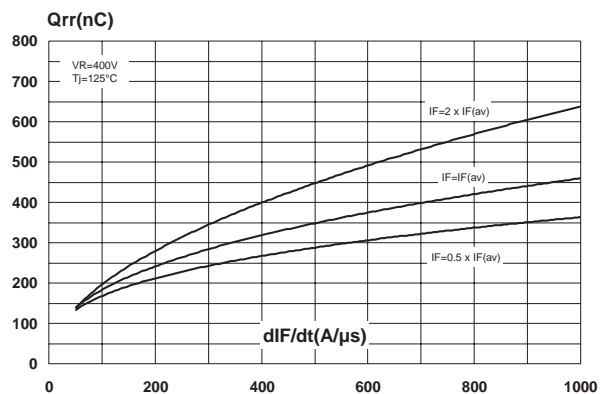
**Fig. 4:** Peak reverse recovery current versus  $dI_F/dt$  (90% confidence, per leg).



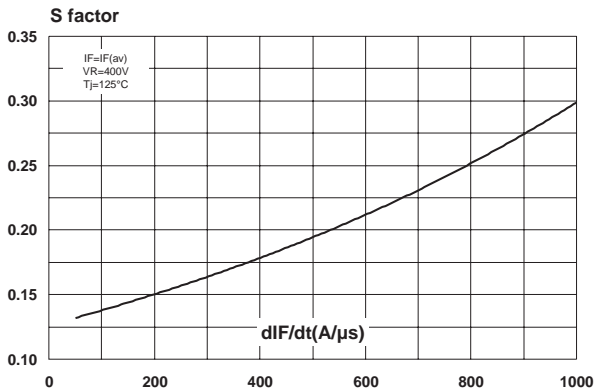
**Fig. 5:** Reverse recovery time versus  $dI_F/dt$  (90% confidence, per leg).



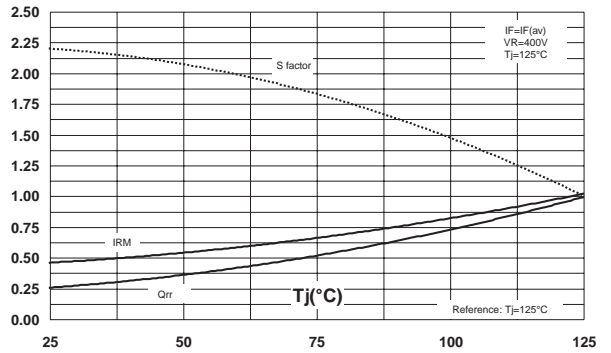
**Fig. 6:** Reverse recovery charges versus  $dI_F/dt$  (90% confidence, per leg).



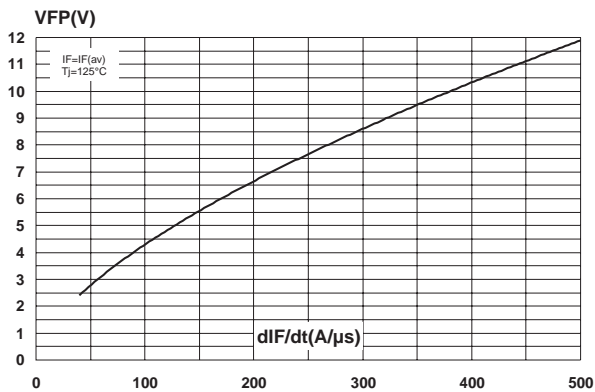
**Fig. 7:** Softness factor versus  $di_F/dt$  (typical values, per leg).



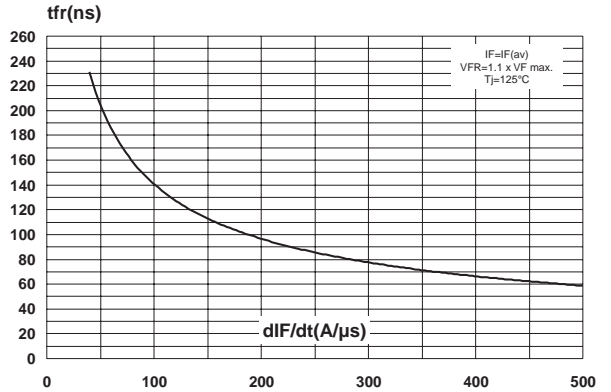
**Fig. 8:** Relative variation of dynamic parameters versus junction temperature.



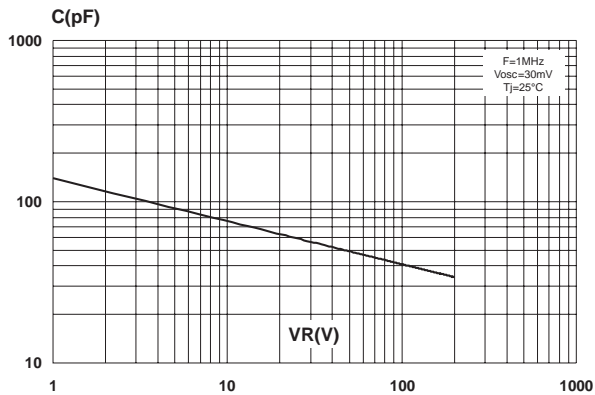
**Fig. 9:** Transient peak forward voltage versus  $di_F/dt$  (90% confidence, per leg).

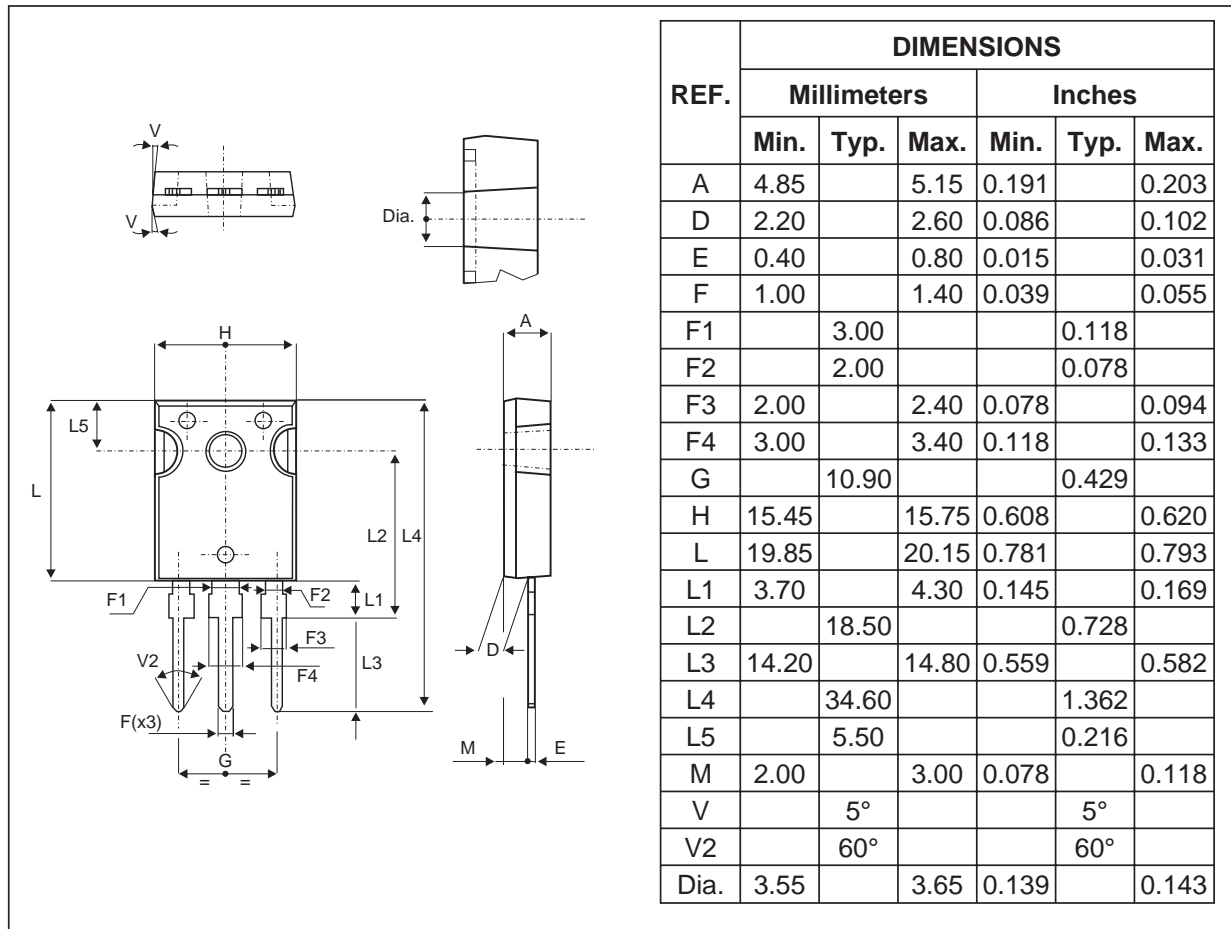


**Fig. 10:** Forward recovery time versus  $di_F/dt$  (90% confidence, per leg).



**Fig. 11:** Junction capacitance versus reverse voltage applied (typical values, per leg).



**PACKAGE MECHANICAL DATA**  
 TO-247


Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STTH30R06CW	STTH30R06CW	TO-247	4.36 g	30	Tube

- Epoxy meets UL 94,V0

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